VS-40TPS16PbF, VS-40TPS16-M3

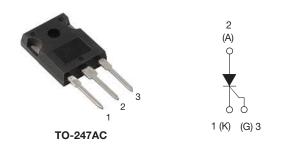
Vishay Semiconductors

RoHS COMPLIANT

HALOGEN

FREE

Thyristor High Voltage, Phase Control SCR, 40 A



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PRODUCT SUMMARY							
Package	TO-247AC						
Diode variation	Single SCR						
I _{T(AV)}	35 A						
V _{DRM} /V _{RRM}	1600 V						
V _{TM}	1.45 V						
I _{GT}	150 mA						
TJ	-40 °C to 125 °C						

FEATURES

- High voltage (up to 1600 V)
- Designed and qualified according to JEDEC[®]-JESD47
- 125 °C max. operating junction temperature
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

 Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	35	А						
I _{RMS}		55	A						
V _{RRM} /V _{DRM}		1600	V						
I _{TSM}		500	A						
V _T	40 A, T _J = 25 °C	1.45	V						
dV/dt		1000	V/µs						
dl/dt		100	A/µs						
TJ		-40 to 125	°C						

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} ∕I _{DRM} AT 125 °C mA						
VS-40TPS16PbF, VS-40TPS16-M3	1600	1700	10						

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PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	$T_{\rm C}$ = 79 °C, 180° conduction half sine wave)	35		
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	А	
Maximum peak, one-cycle	L	10 ms sine pulse, rated V_{RRM} applied		420		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		500		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	Initial T _J = T _J maximum	880	A ² s	
Maximum -t for fusing	1 - 1	10 ms sine pulse, no voltage reapplied		1250		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	12 500	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	v		
High level value of threshold voltage	V _{T(TO)2}	Т _J = 125 °С		1.23	v	
Low level value of on-state slope resistance	r _{t1}	$I_{\rm J} = 125$ C		9.74	mΩ	
High level value of on-state slope resistance	r _{t2}			7.50	11122	
Maximum peak on-state voltage	V _{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	$T_J = 25 \ ^{\circ}C$		100	A/μs	
Maximum holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I_T	= 1 A, T _J = 25 °C	200		
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25$	300			
	1 /1	$T_J = 25 ^{\circ}C$			mA	
Maximum reverse and direct leakage current	I _{RRM} /I _{DRM}	$T_J = 125 \text{ °C}$ $V_R = \text{Rated } V_{RRM}/V_D$	V _R = Rated V _{RRM} /V _{DRM}			
Maximum rate of rise of off-state voltage	dV/dt	$T_{,l} = T_{,l}$ maximum, linear to 80 % V _{DBM} , R_{q}	$T_J = T_J$ maximum, linear to 80 % V_{DRM} , $R_q - k = Open$			

TRIGGERING									
PARAMETER	SYMBOL	TE	ST CONDITIONS	VALUES	UNITS				
Maximum peak gate power	P _{GM}			10	W				
Maximum average gate power	P _{G(AV)}								
Maximum peak gate current	I _{GM}			2.5	А				
Maximum peak negative gate voltage	- V _{GM}			10					
		T _J = - 40 °C		4.0	V				
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5					
		T _J = 125 °C		1.7					
		T _J = - 40 °C		270	mA				
Maximum required DC gate aurrent to triager	I	T _J = 25 °C	Anode supply = 6 V resistive load	150					
Maximum required DC gate current to trigger	I _{GT}	T _J = 125 °C		80					
		$T_{\rm J} = 25 \ ^{\circ}{\rm C}$, for 40	40						
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V	0.25	V					
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM}		6	mA				

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THERMAL AND MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C				
Maximum thermal resistance, junction to case		R _{thJC}	R _{thJC} DC operation						
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W				
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2					
Approvimato weight				6	g				
Approximate weight				0.21	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
	maximum			12 (10)	(lbf ⋅ in)				
Marking device			Case style TO-247AC	40TF	PS16				

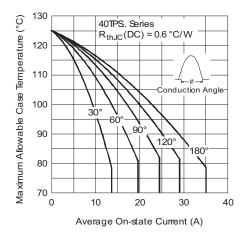


Fig. 1 - Current Rating Characteristics

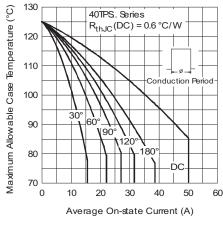


Fig. 2 - Current Rating Characteristics

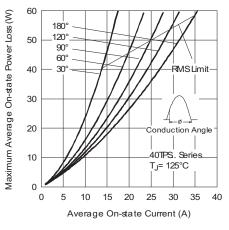


Fig. 3 - On-State Power Loss Characteristics

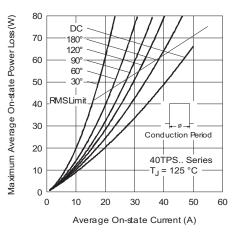


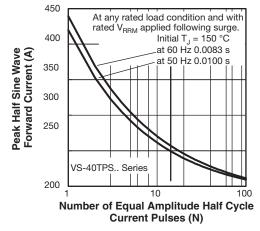
Fig. 4 - On-State Power Loss Characteristics

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Fig. 5 - Maximum Non-Repetitive Surge Current

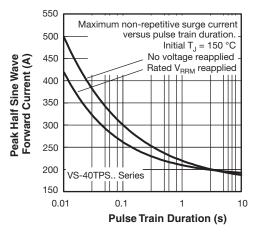


Fig. 6 - Maximum Non-Repetitive Surge Current

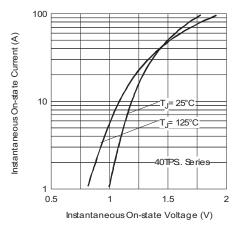


Fig. 7 - On-State Voltage Drop Characteristics

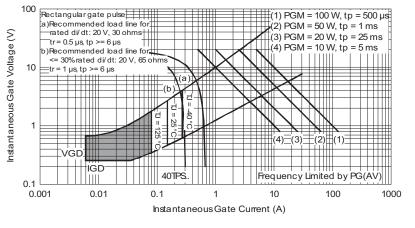


Fig. 8 - Gate Characteristics



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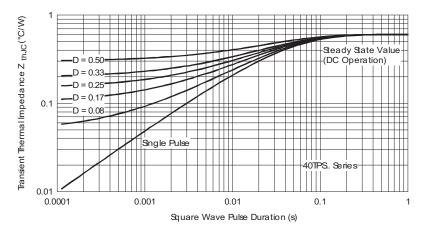


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

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Device code	VS-	40	т	Ρ	S	16	PbF
		(2)	(3)	(4)	(5)	6	(7)
							\bigcirc
	1 - 2 -		•	ng (40 =	tors pro	duct	
	3 -			iguratior	,		
		T =	Thyristo	or			
	4 -		kage:				
			TO-247				
	5 -		e of silic Standar		ery recti	fier	
	6 -				: 1600 V		
	7 -	Envi	ronmen	tal digit:			
		PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant
		-M3	= Halog	en-free,	RoHS	complia	nt, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-40TPS16PbF	25	500	Antistatic plastic tubes						
VS-40TPS16-M3	25	500	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Daut mand in a information	TO-247AC PbF	www.vishay.com/doc?95226					
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007					

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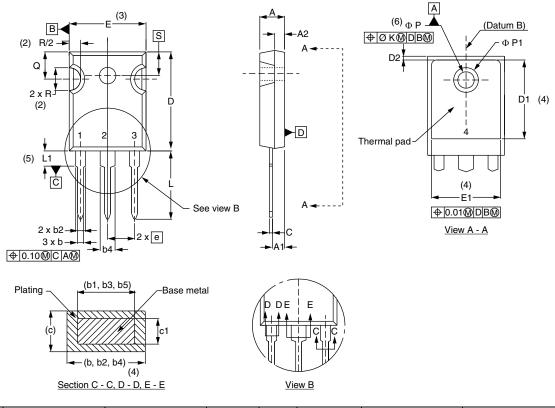
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TO-247AC - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c and Q

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